NSN 5962-01-293-8422

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-293-8422

Body Length:
Between 0.955 inches and 0.990 inches
Body Width:
Between 0.265 inches and 0.300 inches
Body Height:
Between 0.155 inches and 0.175 inches
Operating Tempurature Range:
55.0/+125.0 degrees celsius
Storage Tempurature Range:
65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and burn in and programmable and electrostatic sensitive
nclosure Material:
Ceramic
nclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
nput Circuit Pattern:
10 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
75.00 nanoseconds propagation delay time, low to high level output and 75.00 nanoseconds propagation delay time, high to low level
putput
Memory Device Type:
Pal
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
20 printed circuit
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
Yes - demil/mli
Filg:
A458a0